

MASTR® Progress Line

132-174 MHz, 30-WATT TRANSMITTER MODELS 4ET57C30-41 (ICOM OPTIONS 7301-7316)



SPECIFICATIONS

FCC Filing Designation

Frequency Range

Power Output:

Mobile Power Supply Station Power Supply

Crystal Multiplication Factor

Frequency Stability

Spurious and Harmonic Radiation

Modulation

Audio Frequency Characteristics

Distortion

Deviation Symmetry

Tubes and Transistors

Maximum Frequency Spacing

Duty Cycle:

Mobile

Station

ET-57-C

132-174 MHz

30 watts minimum (20% duty cycle)

10 watts minimum (continuous duty)

12

 $\pm .0002\%$ (-30°C to +60°C)

At least 85 dB below rated power output

Adjustable from 0 to ±5 kHz swing with instantaneous modulation limiting

Within +1 dB to -3 dB of a 6-dB/octave peremphasis from 300 to 3000 Hz per EIA standards. Post limiter filter per FCC and EIA.

Less than 5%

0.5 kHz maximum

30-Watt Transmitter with no Options:

2 tubes

6 transistors

4 diodes

0.4%

20% Transmit (one minute transmit, four minutes

Continuous

*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

TABLE OF CONTENTS

SPECIFICATIONS Cover	c i
DESCRIPTION	1
CIRCUIT ANALYSIS	1
Power Inputs Integrated Circuit Oscillator Module (ICOM) Audio Amplifiers and Limiter Phase Modulator Amplifiers and 1st and 2nd Multipliers 3rd Multiplier Power Amplifier Channel Guard	1 2 2 2 2 3 3 3
MAINTENANCE	4
Disassembly Alignment Procedure Test Procedures	4 5 6
Power Output	6 6 6
Troubleshooting	7
OUTLINE DIAGRAM (with resistance readings)	8
SCHEMATIC DIAGRAM (with voltage readings)	9
PARTS LIST	
Transmitter	10 11
PRODUCTION CHANGES	10
ILLUSTRATIONS	
Figure 1 Block Diagram	1
Figure 2 Removing Top Cover for Servicing	4
Figure 3 Removing Bottom Cover for Servicing	4

WARNING -

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

DESCRIPTION

MASTR Progress Line FM Transmitter Types ET-57-C is a crystal-controlled, phase modulated transmitter designed for one-, two-, or four-frequency operation within the 132-174 megahertz band. The transmitter consists of the following modules:

- Transistorized Exciter Board, with audio, oscillator, modulator, amplifier and multiplier stages.
- Integrated Circuit Oscillator Module (ICOM),
- Tubed multiplier and power amplifier stages.
- Optional Channel Guard Low-Pass Filter.

All input leads to the transmitter are individually filtered by the 20-pin feed-through by-pass connector J101. The output passes through a four-section, low-pass filter that features good shielding between sections, and Teflon capacitors for fail-free operation with an open or shorted antenna.

CIRCUIT ANALYSIS

Eight silicon transistors and only two tubes are used in the transmitter. When used with the mobile power supplies, the transmitter has a minimum power output of 30 watts. When used as an exciter with high power stations, the minimum power output is 10 watts. The frequency of the plugin ICOM modules ranges from 11 to 14.5 megahertz, and the crystal frequency is multiplied 12 times.

A centralized metering jack (J102) is provided for use with GE Test Sets 4EX3A10 or 4EX8K10,11. The Test Set meters the multiplier, amplifier and PA stages as well as filament and regulated supply voltages. The metering jack also provides access to receiver audio, microphone and push-to-talk leads.

POWER INPUTS

The following supply voltages are connected for the power supply to the transmit-

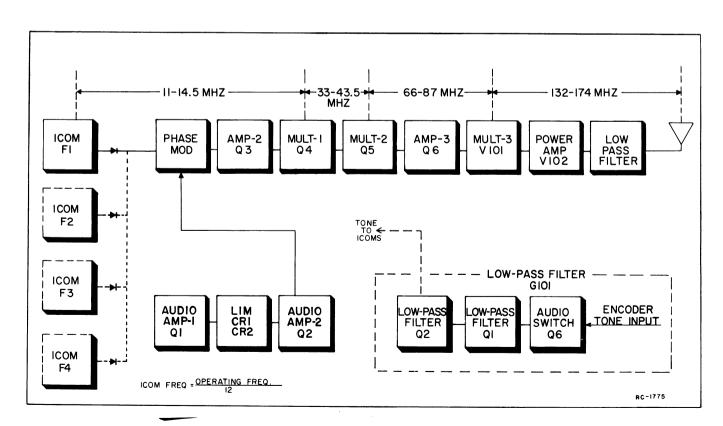


Figure 1 - Transmitter Block Diagram

ter through the 20-pin by-pass connector J101:

Pin 3 - Filament voltage

Pin 4 - +300 volts MULT B+

Pin 5 — +450 volts PA B+ with mobile supplies (+300 volts PA B+ for driver use with station supplies)

Pin 8 - -45 volts bias

Pin 14 — +10 volts for Channel Guard option

Pin 15 - -20 volts for Exciter Board and ICOM Module

ICOM MODULE

ICOM module Model 4EG25Al0 consists of a crystal-controlled Colpitts oscillator, a voltage regulator, a Channel Guard tone modulator and a buffer output stage. The entire module (including crystal) is enclosed in a dust-proof aluminum can, with the ICOM frequency and the transmitter operating frequency printed on the top. Access to the oscillator trimmer is obtained by prying off the plastic GE decal on the top of the can.

The oscillator frequency is temperature-compensated at both ends of the temperature range to provide instant frequency compensation, with a frequency stability of $\pm 0.0002\%$.

In single-frequency transmitters, a keying jumper from H1 to H2 (on the exciter board) connects the ICOM to ground. This drops the -20 volts exciter supply through voltage dividers R19 and R20 to provide -10 volts to operate the ICOM. With the ICOM operating, diode CR3 is forward biased and the oscillator output is applied to the modulator stage.

In multi-frequency transmitters, up to three additional ICOM modules can be plugged into the exciter board. The single-frequency keying jumper is removed, and the proper frequency is selected by switching the ICOM keying lead to ground by means of a frequency selector switch on the control unit.

For transmitters equipped with Channel Guard, tone from Encoder Gl01 is applied to the ICOM through Channel Guard Mod Adjust R1002. The oscillator output is frequency modulated by the Channel Guard tone.

- CAUTION -

All ICOM modules are individually compensated at the factory, and cannot be repaired in the field. Any attempt to remove the ICOM cover will void the warranty.

AUDIO AMPLIFIERS AND LIMITER

An audio signal from the microphone is coupled through C1 to the base of Class A audio amplifier Q1. The design of the microphone, in conjunction with C2 and R3, produces a 6-dB audio pre-emphasis. RF decoupling is provided by C45.

The amplified audio signal is RC coupled to the diode limiters, CR1 and CR2. These diodes operate in series and are normally in a forward conducting stage. An audio signal of sufficient amplitude to cause limiting takes the diodes out of conduction, so that one diode conducts only on positive cycles and the other conducts only on negative cycles.

Following the limiter stage is a second Class A amplifier, Q2. The output of Q2 is coupled through MOD ADJUST potentiometer R12 to a combined post-limiter filter and de-emphasis network. This network consists of C4, C7, C8, C9, R13, R14, R15 and R18. The output of the filter and deemphasis network is applied directly to the phase modulator.

PHASE MODULATOR

The phase modulator uses varactor CV1 (voltage variable capacitor) in series with tunable coil L1/L2. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator varies the bias of CV1, resulting in a phase-modulated output. The output of the modulator is coupled through blocking capacitor C14 to the base of the second amplifier.

AMPLIFIERS AND 1ST AND 2ND MULTIPLIERS

The second amplifier (Q3) isolates the modulator from the loading effects of the first multiplier and provides amplification. The output is coupled through T6 to the first multiplier.

Following Q3 are two inductively-coupled Class C, common-emitter multiplier stages (Q4 and Q5). Q4 is a tripler, with collector tank T1 tuned to three times the crystal frequency. Metering resistors R31 and R42 are for metering the MULT-1 stage at centralized metering jack J102.

Q5 operates as a doubler stage, with collector tank T3 tuned to six times the crystal frequency. Resistors R33 and R40 are for metering the MULT-2 stage at J102. The output of Q5 is inductively coupled through T3 and T4 to amplifier Q6. In 450-470 megahertz transmitters, capacitor C29 provides some high-side capacitive coupling.

Third amplifier Q6 is a neutralized straight-through amplifier. Feedback through C35 from the output link on T5 provides neutralization. This stage is metered

at J102-3 across R37. The output is coupled to the grid tank of multiplier V101.

3RD MULTIPLIER

The output of the transistorized Exciter is coupled by a short length of RF cable to the grid tank (Z101/Z102) of beam pentode V101. This stage operates as a doubler with the plate tank tuned to twelve times the crystal frequency.

The grid of V101 is metered through metering resistors R1 and R2 at J102-5. The combination of R1, R2 and R3 drops the bias voltage to approximately -18 Volts to protect V101 against loss of drive. Plate voltage is supplied through L101.

When measuring grid current to V101, there will be a residual reading of approximately 0.18 Volts without any drive. This is caused by the presence of fixed bias voltage to the grid of the tube.

POWER AMPLIFIER

The output of the MULT-3 stage is coupled to the grid of the compactron beam power amplifier (V102) by a pi-network consisting of C104, L107/L108 and C118. The grid tank is tuned by C118 (PA GRID), and current is metered at J102-6 and J102-14 by measuring the voltage drop across R11. Bias voltage (-45 Volts) is applied to the PA grid through R10, R11 and L102/L103. There is no residual reading on the PA.

-WARNING

The meter leads are at plate potential (high B+) when metering the PA plate at J102-1 and J102-9.

Placing the TUNE-OPERATE switch (S102) in the OPERATE position applies 300 Volts to A117-J3 and -J7. The 300 Volts appearing on each side of R13 effectively short the resistor out of the circuit, and R14 and R15 are in series for normal operation of V102. When S102 is in the TUNE position, the screen voltage is applied to A117-J3 only. Now, dropping resistors R13, R14 and R15 are in series, to reduce the screen of voltage. This reduces the plate dissipation of V102 while tuning the power amplifier stage. Capacitors C107, C108 and C109 neutralize the PA stage.

Antenna coupling is achieved by varying the coupling between L102/L110 and L111/L112. The antenna circuit is tuned by C112.

The RF output from the antenna coil is fed to low-pass filter FL101. This filter has a low insertion loss and a harmonic attenuation of at least -50 dB through all harmonics. The filter output is fed to the antenna changeover relay located on the front of the system frame.

CHANNEL GUARD

Low Pass Filter (G101)

In encode-decode combinations, low-

pass filter Gl01 is assembled on a printed wiring hoard that mounts on the underside of the MASTR transmitters. The filter is supplied by a regulated +10 Volts and a regulated -20 Volts. The +10-Volts is applied continuously (even in the STANDBY position), and the -20 Volts is applied only when the transmitter is keyed.

Keying the transmitter applies the encoder tone (from the receiver) to low-pass filter Gl01. Transistors Ql and Q2 form a two-section, active low-pass filter that reduces tone distortion and power sup-ply ripple. Q6 operates as a tone switch, applying the tone input to the filter whenever +10 Volts is applied to J1 (Q6 base). Thermistor RT1 keeps the output constant over wide variations in temperature. The filter output is coupled to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit of the OFF position, or by removing the microphone or handset from the optional hang-up bracket.

-NOTE -

If Channel Guard decode only is desired, disconnect the Encoder Tone Input from J6 on the low-pass filter.

Encoder Model 4EH17A10 (Optional)

In encode only combinations, encoder Model 4EH17A10 mounts on the underside of the MASTR transmitter. The encoder is supplied by a regulated +10 volts and a regulated -20 Volts. The +10 Volts is applied to Q3, Q4 and Q5 continuously (even in the STANDBY position). The -20 Volts is applied to Q1 and Q2 only when the transmitter is keyed.

The encoder tone is provided by selective oscillators Q3 and Q4, which oscillate continuously at a frequency determined by the tone network (FL1). Negative feedback, applied through the tone network to the base of Q3, prevents any gain in the stage except at the desired encode frequency.

Thermistor-resistor combination R14 and RT2 provides temperature compensation for the oscillator output. Limiter diodes CR1 and CR2 keep the tone amplitude constant.

Keying the transmitter applies -20 Volts to the two-stage, active low-pass filter (Ql and Q2) turning them on. The oscillator output is then coupled through emitter-follower Q5 to the low-pass filter. Thermistor RT1 keeps the filter output constant over wide variations in temperatures.

The output of the filter is applied to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or by removing the microphone or handset from the optional hang-up bracket.

MAINTENANCE

DISASSEMBLY

To service the transmitter from the top-

- 1. Pull locking handle down and pull radio about one inch out of mounting frame.
- 2. Pry up cover at rear of transmitter.
- 3. Slide cover back and lift off.

To service the transmitter from the bottom-

- Pull locking handle down. Pull radio out of mounting frame.
- Remove two screws in bottom cover. Pry up at back of transmitter.
- 3. Slide cover back and lift off.



To replace tubes, loosen screws holding tube shields and slide shields off.

To remove transmitter from system frame-

- 1. Loosen the two retaining screws in the front casting (see Figure 2) and pull casting away from the system frame.
- 2. Remove the four screws in the back cover.
- Remove the two screws holding the transmitter at each end of the system frame.
- 4. Disconnect the antenna jack in front of the transmitter and the 20-pin feed-thru connector at the back of the transmitter, and slide the unit out of the system frame.

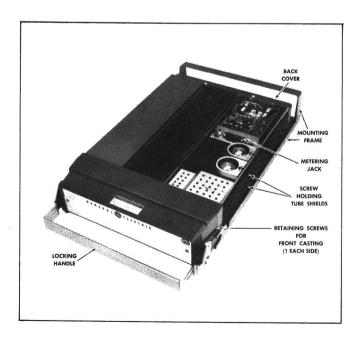


Figure 2 - Top Cover Removed

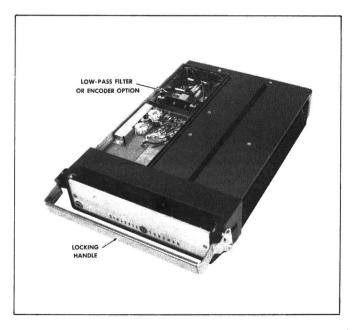


Figure 3 - Bottom Cover Removed

MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R12) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

TEST EQUIPMENT

- 1. Audio oscillator
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set, Model 4EX3Al

PROCEDURE

- Connect the audio oscillator and the meter across audio input terminals J5 (Green-Hi) and J6 (Black-Lo) on GE Test Set or across J1 (Mike High) and J2 (Mike Low) on the Exciter Board.
- 2. Apply a 1.0-volt signal at 1000 Hz to Test Set or across Jl and J2 on Exciter Board.
- 3. For transmitters without Channel Guard, set the MOD ADJUST (R12) for a 4.5-kilohertz swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set the Channel Guard MOD ADJUST (R1002) for 0.75-kHz tone deviation. Then repeak L1/L2 and L3/L4 as shown in Step 1 of Transmitter Alignment Procedure. Reset tone deviation to 0.75-kHz deviation. Remove the tone to the transmitter by unplugging leads to J7 and J8 on Exciter Board, or by switching to a non-Channel Guard frequency in multifrequency units. Next, apply a 1.0 volt signal at 1000 Hz and set MOD ADJUST (R12) for 3.75-kHz deviation (4.5 kHz minus 0.75-kHz tone deviation).
- 5. For multi-frequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

PA PLATE POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA Plate voltage and the plate current indication, and using the following formula:

$P_i = \frac{Plate\ Voltage\ x\ Plate\ Current\ Indication}{4.38}$

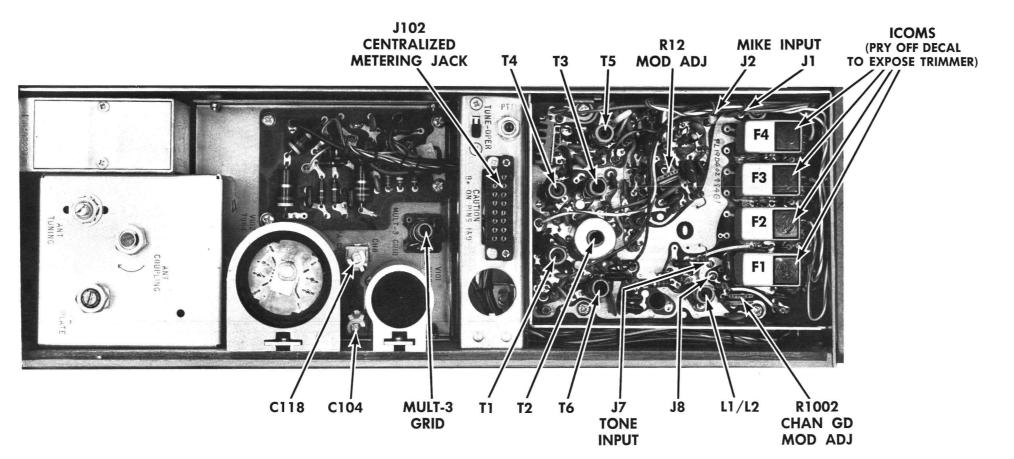
where:

Pi is the power input in watts.

Plate voltage is measured with GE Test Set in Position G, using the 1000-volt scale (or measured from J102-1 to -16 with multimeter).

Plate current indication is measured with GE Test Set in Position G, using the TEST 1 scale (or measured from J102-1 to -9 with multimeter).

4.38 is the value of the plate current metering resistor in ohms.



EQUIPMENT REQUIRED

TRANSMITTER ALIGNMENT

- 1. General Electric Test Set Model 4EX3AlO, Station Meter Switching Panel, or a 20,000 ohm-per-volt Multimeter with a 1-volt scale.

 PRELIMINARY CHECKS AND ADJUSTMENTS
 - Place ICOM(s) (operating frequency : 12) into proper socket. Do not adjust ICOM trimmer.
 If multi-frequency transmitter, tune transmitter on channel with the highest frequency.
 - 2. Place the TUNE-OPERATE switch (S102) in the TUNE position.
 - 3. Connect GE Test Set to the Transmitter Centralized Metering Jack J102. If using Multimeter, connect the positive lead to J102-16 (Ground) except for Steps 6 through 15.
 - 4. For a large change in frequency or a badly mis-aligned transmitter, set the slugs in the Exciter coils at the bottom of the coil form (closed to the printed board), and the slug of MULT-3 GRID (Z101/Z102) at the top of the coil form.
 - 5. All adjustments are made with the transmitter keyed.

METERING POSITION

Do not exceed a maximum meter reading of 1 volt on any adjustment while aligning the transmitter

STEP	4EX3A10	Multimeter - at J102	TUNING CONTROL	TYPICAL METER READING	PROCEDURE
			<u> </u>	EXCITER	BOARD .
1.	A	Pin 10	T6 and L1/L2	0.55 v (0.4 v Minimum)	Tuning the modulator is a critical adjustment. Carefully tune T6 and L1/L2 alternately for maximum meter reading. If no peak is obtained when tuning T6, set the slug in L1/L2 to a different position and re-tune T6.
2.	A (MULT-1)	Pin 10	Т1	See Pro- cedure	Tune Tl for a small dip in meter reading (not required unless changing frequency.
3.	B (MULT-2)	Pin 2	T2, T1 and T3	0.65 v (0.5 v Minimum)	Tune T2 and then T1 for a maximum meter reading. Then tune T3 for minimum meter reading (not required unless changing frequency).
4.	C (AMPL-3)	Pin 3	T4, T3 and T5	0.6 v (0.5 v Minimum)	Tune T4 and then T3 for a maximum meter reading. Then tune T5 for minimum meter reading (not required unless changing frequency).
			M	ULT-3 AND POWER	AMPLIFIER
5.	D (MULT-3)	Pin 4	MULT-3 GRID(Z101/ Z102)	0.6 v (0.5 v Minimum)	Tune MULT-3 GRID for maximum meter reading.
6.	F (PA PLATE)	Pin 14 (+) and Pin 6 (-)	C118 and C104	0.4 v (0.2 v Minimum)	Alternately tune Cl18 and Cl04 for maximum meter reading. Peak Cl04 as small changes in Cl18 reading are made.
7.					Rotate ANT COUPLING fully counterclockwise.
8.	G (PA PLATE)	High B-plus on Pin 1 (+) and Pin 9 (-)	WARNING Pins 1 and 9 PA PLATE (C110)	Minimum	Carefully tune PA PLATE for minimum meter reading. Then for multi- frequency transmitters, alternately switch from the highest to the lowest frequency and adjust PA PLATE to an intermediate frequency so that readings are approximately equal on both frequencies.
9.					Place S102 in the OPERATE position.
10.	G (PA PLATE)	Pin 1 (+) and Pin 9 (-)	ANT COUPLING	See Pro- cedure	Rotate ANT COUPLING clockwise until meter reading rises slightly. In multi-frequency transmitters, switch to the lowest frequency before making this adjustment.
11.	G (PA PLATE)	Pin 1 (+) and Pin 9 (-)	ANT TUNING (C112)	Maximum	Adjust ANT TUNING for maximum meter reading.
12.	G (PA PLATE)	Pin 1 (+) and Pin 9 (-)	ANT COUPLING	0.7 v	Adjust ANT COUPLING for meter reading of 0.7 volt.
13.	G	Pin 9 (-)		Tune ANT TUNING for maximum meter reading.	
14.	F (PA GRID)	Pin 14(+) and Pin 6 (-)	C118 and C104	Maximum	For single-frequency transmitters, alternately tune C118 and C104 for maximum meter reading. For multi-frequency transmitters: Tune C104 for equal grid currents on the highest and lowest frequencies.
15.	G (PA PLATE)	Pin 1 (+) and Pin 9 (-)			When properly aligned, the reading on the highest channel should be equal to, or slightly lower than reading on lowest frequency (05 volt maximum).

ICOM FREQUENCY ADJUSTMENT

First, check the transmitter frequency to determine if any adjustment is required. The frequency should be checked with a frequency meter or counter having an accuracy of 0.4 part-per-million (PPM), and with the ICOM module at $80^{\circ}F$ ($\pm 4^{\circ}F$) or $26.5^{\circ}C$ ($\pm 2^{\circ}C$) when possible. The ICOM temperature can be determined by taping a mercury thermometer to the side of the ICOM.

The ICOM case is at -20 volts DC. Be careful not to short

the case to ground.

NOTE -

If an adjustment is required, use one of the following procedures:

 $\underline{\text{If the ICOM}}$ is stabilized at $80\,^{\circ}\text{F}$, pry off the GE emblem and adjust the ICOM trimmer for correct transmitter operating frequency.

If the ICOM is not stabilized at $80^{\circ}F$, pry off the GE emblem and check for a color dot on the top of the can. This color dot indicates which correction curve to use in setting the unit on frequency (see Figure 4). Next, tape a thermometer to the ICOM and check the temperature when the thermometer is stabilized. Then proceed as shown in the following example:

- Assume that the ICOM is marked with a green color dot and the temperature reading is 50°F. At that temperature, the green curve shows a correction factor of approximately +1.5 PPM. (At 132 MHz, 1 PPM is 132 Hz. At 174 MHz, 1 PPM is 174 Hz.)
- 2. With a transmitter operating frequency of 150 MHz, adjust the ICOM trimmer for a reading of +225 Hz (+1.5 x 150) higher than the licensed operating frequency.
- 3. If a negative correction factor is obtained (at temperatures above 80°F), adjust the ICOM trimmer for the indicated PPM lower than the operating frequency.

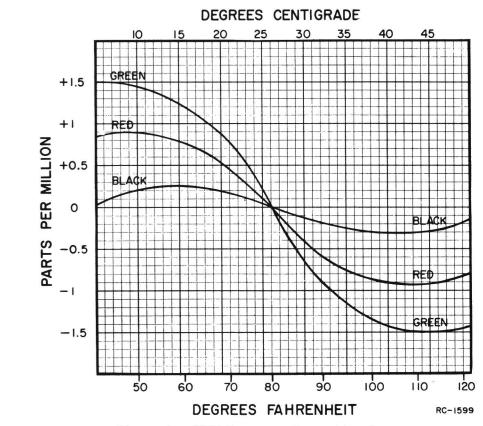


Figure 4 - ICOM Frequency Correction Curve

ALIGNMENT PROCEDURE

132—174 MHz, 30-WATT TRANSMITTER MODELS 4ET57C30-41

Issue 1

LBI-3980

TEST PROCEDURES

These Test Procedures are designed to assist you in servicing a transmitter that is operatingbut not properly. Problems encountered could be low power output, low B plus, tone and voice deviation, defective audio sensitivity and modulator adjust control set too high. By following the sequency of test steps starting with Step 1, the

defect can be quickly localized. Once a defect is pin-pointed, refer to the "Service Check" and the additional corrective measures included in the Transmitter Troubleshooting Procedure. Before starting with the Transmitter Test Procedures, be sure the transmitter is tuned and aligned to the proper operating frequency.

TEST EQUIPMENT REQUIRED

for test hookup as shown:

- 1. Wattmeter similar to:
- 2. VTVM similar to:

3. Audio Generator similar to:

Bird # 43 Jones # 711N Triplett # 850 Heath # 1M-21

GE Model 4EX6Al0 or Heath # 1G-72

4. Deviation Meter (with a .75 kHz scale) similar to:

> Measurements #140 Lampkin # 205A

5. Multimeter similar to:

GE METERING TEST SET MODEL 4EX3A10 or Triplett # 631 or 20,000 ohms-per-volt voltmeter

STEP 1

POWER MEASUREMENT

TEST PROCEDURE

1. Connect transmitter output to wattmeter as shown below:



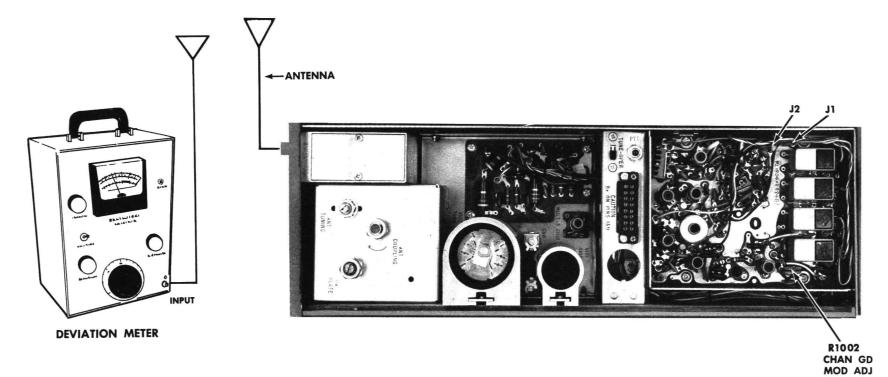
SERVICE CHECK

Refer to Service Hints on Transmitter Troubleshooting Procedure.

STEP 2

TONE DEVIATION WITH CHANNEL GUARD **TEST PROCEDURE**

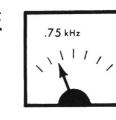
1. Set up Deviation Meter and monitor output of transmitter as shown below:



- 2. Unplug the MIC HI terminal from Jl on Transmitter Exciter Board.
- Key transmitter and check for 0.75-kHz deviation. If reading is low or high, adjust Channel Guard MOD ADJUST (R1002) for a reading of 0.75-kHz.

NOTES: -- The Channel Guard MOD ADJUST (R1002) may be adjusted for deviations up to 0.80 kHz for tone frequencies from 71.9 Hz to 82.5 Hz, and deviations up to 1.0 kHz for all tone frequencies above 82.5 Hz.

- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be peaked carefully to insure proper performance. (Refer to Steps 1 and 2 in the Transmitter Alignment Chart).
- 2. The Tone Deviation Test Procedures should be repeated everytime the Tone Frequency is changed.



DEVIATION METER

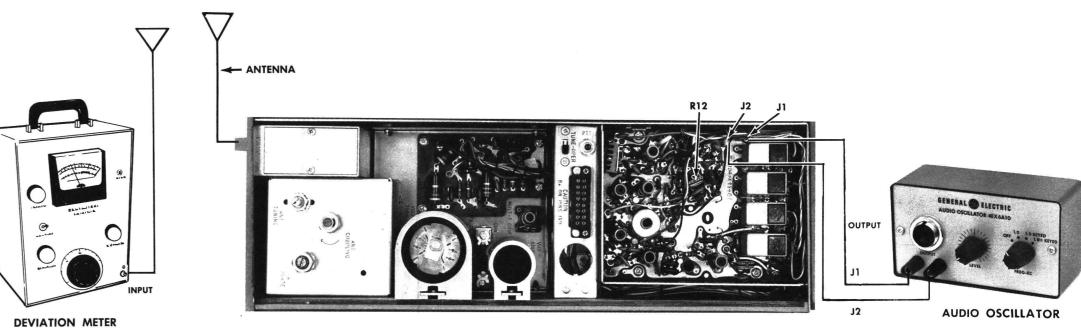
SERVICE CHECK

If the 0.75-kHz deviation is not obtainable when adjusting R1002, adjust R12 until 0.75 kHz is obtained.

STEP 3

VOICE DEVIATION AND SYMMETRY TEST PROCEDURE

- 1. Unplug the High and Low Mike leads from the Exciter Board Jacks Jl and J2.
- Connect test equipment to transmitter as shown below:



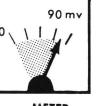
- 3. Set the generator output to 1.0 VOLTS RMS and frequency to 1 kHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency.
- 5. Deviation reading should be ± 4.5 kHz.
- 6. Adjust "Modulation Adjust Control" R12 until deviation reads 4.5 kHz on plus (+) or minus (-) deviation, whichever is greater. This adjustment should be made with the correct level of tone applied on Channel Guard transmitters.



NOTES:--MASTR transmitters are adjusted for 4.5 kHz deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5.0 kHz under the worst conditions of frequency, voltage and temperature.

If the deviation reading plus (+) and minus (-) differs by more than 0.5 kHz, check the following:

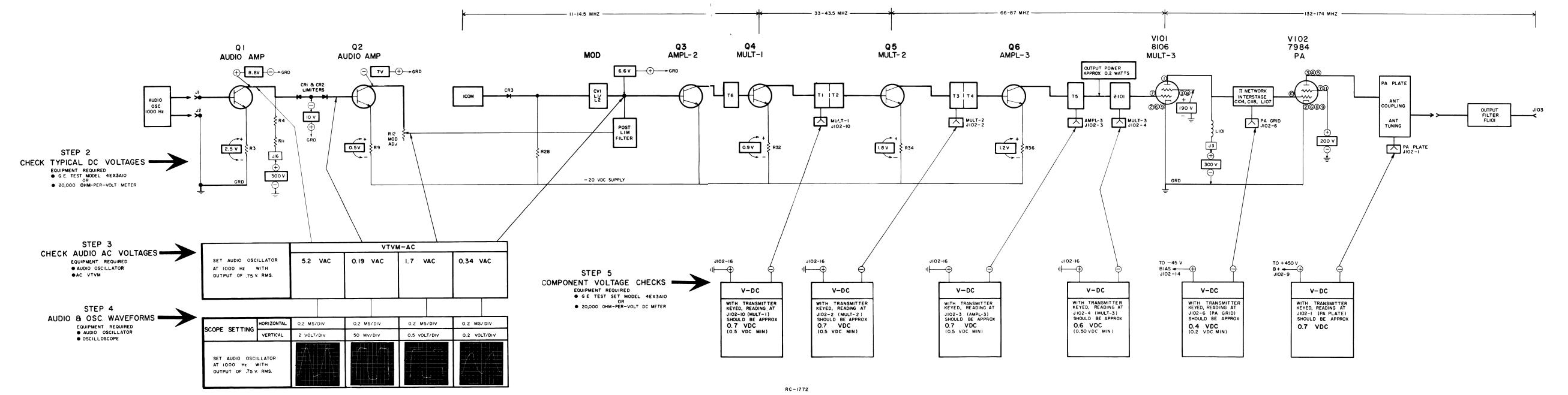
- 1. Recheck Step 1 as shown in the Transmitter Alignment Chart.
- Check Audio Sensitivity by reducing generator output until deviation falls to 3.0 kHz. Voltage should be LESS than 100 millivolts.



2. Key transmitter and check wattmeter for minimum reading of 30 watts.

STEP I - QUICK CHECKS

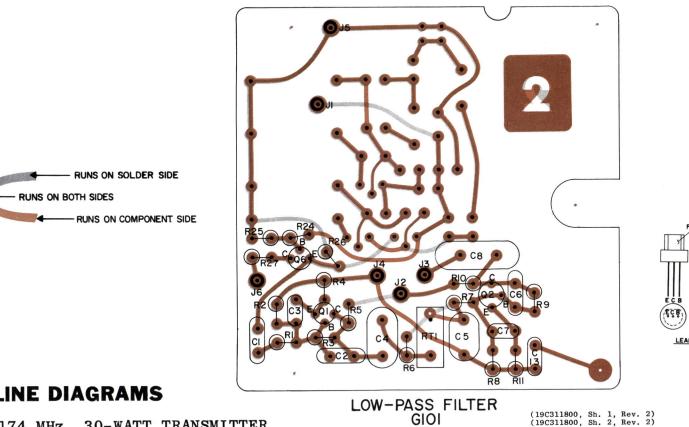
	С	CHECK VOLTAGES AT CENTRALIZED METERING JACK J102 Multimeter = pin numbers GE Test Set = A-G positions								
POWER OUTPUT	Pins Pins Pins Pins Pins Pins Pins Pins									
Low	0.7 v	0.65 v	0.65 v	0.6 v	0.4 v	0.7 v	Weak 7984			
0	0.7 v	0.65 v	0.65 v	0.6 v	0	0	Open 7984			
Low	0.7 v	0.65 v	0.65 v Low	or 0.6 v	Low or neg.		Weak 8106			
0	0.7 v	0.65 v	0.65 v	0.15 v	0	0.4 v	8106 Fil. open			
0	0.7 v	0.65 v	0.65 v	0.15 v	0	0	Open Fil. Fuse			
0	0.7 v	0.65 v	0 or over	0.15 v	0	0.4 v	Defective Q8			
0	0.7 v	0 or over 1.0 v	0	0.15 v	0	0.4 v	Defective Q7			
0	Over 1.0 v	0	0	0.15 v	0	0.4 v	Shorted Q6 or Open Q5			
0	0	0	0	0.15 v	0	0.4 v	Defective Q3-Q6 or Modulator (See note A)			
NOTE A	Localize	trouble by	checking:		<u> </u>					
1.	-20 volt DC supply at J102-12-16.									
2.	Measure 12.1 VDC across Q4 emitter resistor R31 (1500 ohms), then:									
(a)	Remove crystal - a slight variation in R31 voltage reading indicates Q3 and Q4 stages operating properly.									
(b)	If no vo	ltage is mea	sured, check	keying lea	ds CR3-CR6,	Q3, Q4.				
(c)	With cry indicate	stal removed s Q5 and Q6	d, short Q5 ba are operating	se to emit	tter. A vol Defect ma	tage readi y be in Mo	ng above 1.0 volt dulator.			
(d)	If modul	ator is defe	ective, check	voltage va	riable diod	es CV1 and	CV2.			



TROUBLESHOOTING PROCEDURE

132-174 MHz, 30-WATT TRANSMITTER MODELS 4ET57C30-41

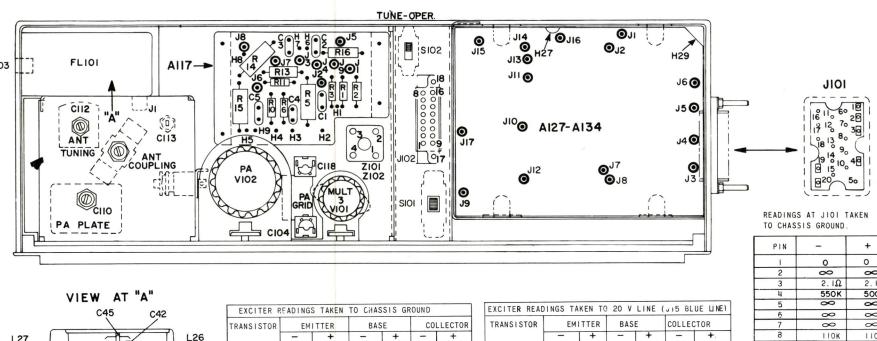
LEAD IDENTIFICATION



OUTLINE DIAGRAMS

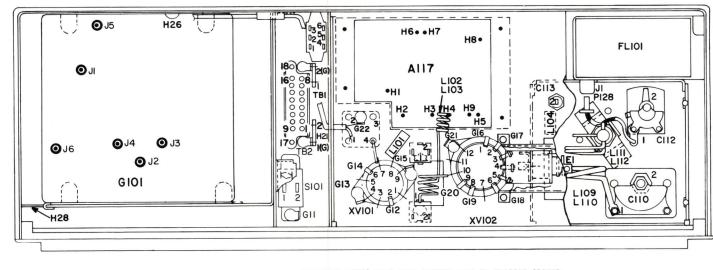
132-174 MHz, 30-WATT TRANSMITTER MODELS 4ET57C30-41

TOP VIEW



VIEW AT A														
C45 C42	EXCITER F	EADING	STAKEN	TO CHAS	SIS GF	ROUND		EXCITER READ	INGS TA	KEN TO	20 V	LINE (J 15 BL	UE LINE
	TRANSISTOR	EM	ITTER	BAS	E	СО	LLECTOR	TRANSISTOR	EM	TTER	BASI	E	COLLEC	TOR
27 L26		-	+	-	+	-	+		-	+	_	+	_	+.
	Q١	5.8K	5.9K	140K	HK	60K	30K	QI	9.5K	IOK	145K	17.2K	63K	45K
	Q2	4. IK	2.8K	70K	7.5K	8.7K	9.5K	Q2	450	450	68K	3.5K	11.5K	13.5K
[2 2 2	Q3	3.4K	115	62K	5.7K	3.7K	3.8K	Q3	0	0	68K	3.2K	7 K	8K
C44	QH	3.6K	2.3K	3.4K	2. IK	165	165	QЧ	13	120	0	0	2.2K	3.7K
	Q5	3.6K	2.3K	3.4K	115	200	210	Q5	54	120	0	0	52	3.7K
J103 L25	Q6	3.5K	2. IK	3.5K	2.2K	70	70	Q6	22	25	47	45	2.2K	3.5K
711			+											
L28 C43 C41														

BOTTOM VIEW



READINGS TAKEN FROM TUBE SOCKET PINS TO CHASSIS GROUND

-	PIN	1	2	3	4	5	6	7	8	9	10	1.1	12
-	XVIOI	5 5 0 K	0	550K	0	2.10	0	39K	50K	0			
	XV102	0	0	~	∞	~	0	550K	0	О	IIOK	550K	2. ΙΩ

★ IST READING FOR SINGLE FREQ. 2ND READING FOR MULTI-FREQ.

RESISTANCE READINGS ALL READINGS ARE TYPICAL READINGS MEASURED WITH A 20.000 OHM-PER-VOLT METER AND JIOI DISCONNECTED.

OR SIGNS SHOW METER LEAD

FOR READINGS OF: USE SCALE:

X 100,000

GROUNDED.

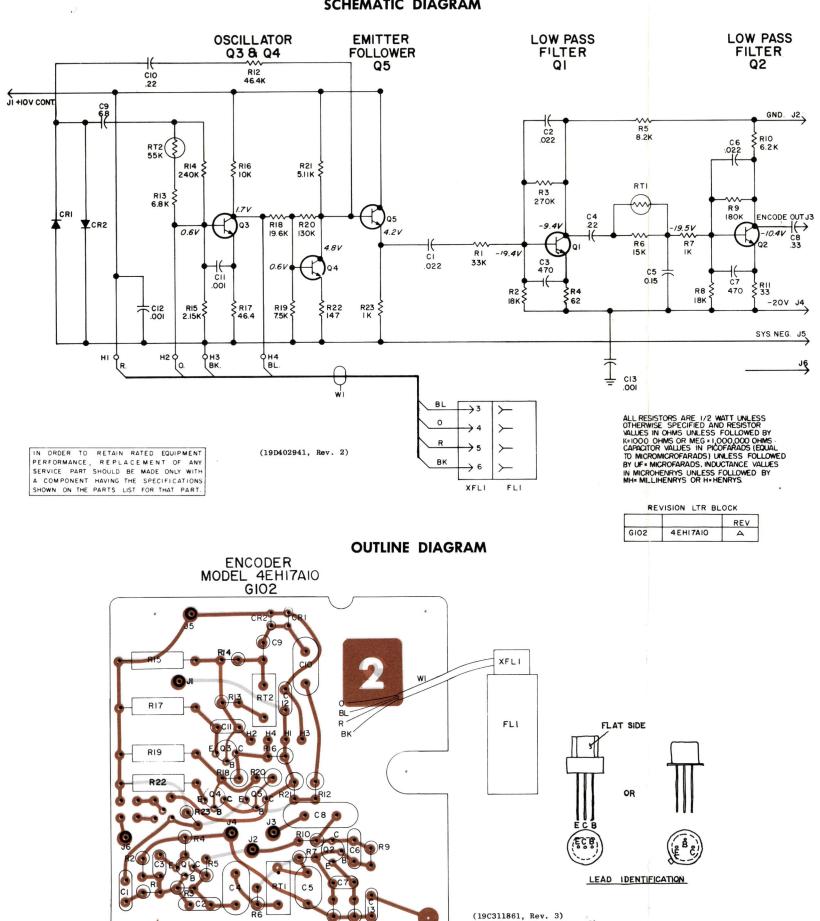
1-100Ω

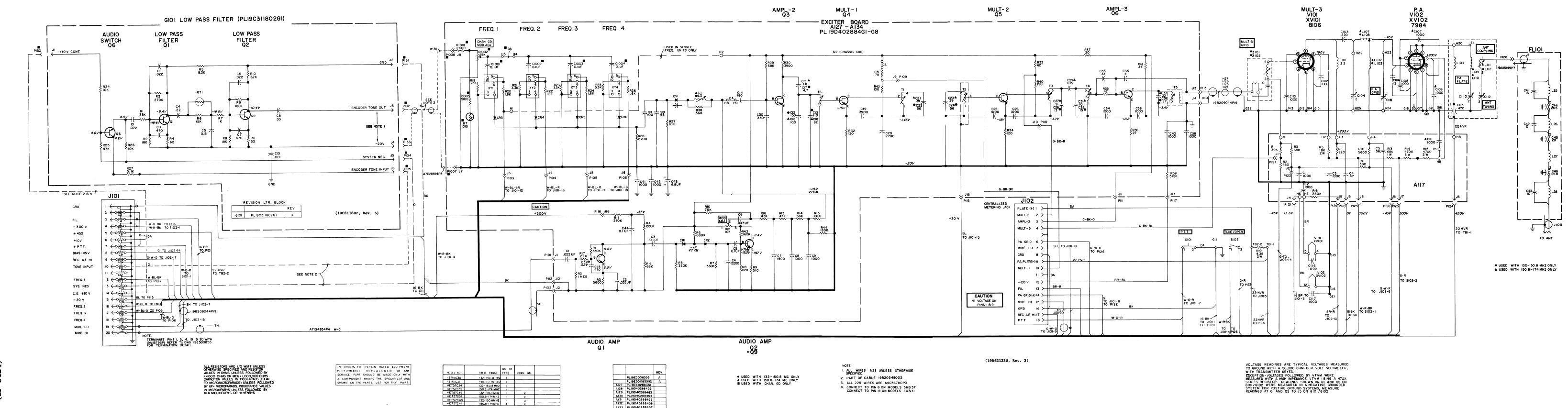
1K-50KΩ 50-∞Ω

(19D413261, Rev. 3)

CHANNEL GUARD ENCODER MODEL 4EH17A10

SCHEMATIC DIAGRAM





SCHEMATIC DIAGRAM

132-174 MHz, 30-WATT TRANSMITTER MODELS 4ET57C30-41

LBI-3980

PARTS LIST

LBI-3977B 132-174 MHz TRANSMITTER MODELS 4ET57C30-4ET57C41

C3 C4 5490008Pl19 Silver mica: 47 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. C5 5490008Pl21 Silver mica: 56 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	SYMBOL	GE PART NO.	DESCRIPTION
C1 thru C3	A117		
C1 thru C3		1	
Electro Motive Type DM-15. S490008P121 Silver mica: 56 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. Silver mica: 56 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15. Contact, electrical; sim to Bead Chain L93-3. Composition: 39,000 ohms ±10%, 1/2 w. Composition: 430 ohms ±5%, 1/2 w. Composition: 18,000 ohms ±10%, 1/2 w. Composition: 18,000 ohms ±10%, 1/2 w. Composition: 220 ohms ±10%, 1/2 w. Composition: 330 ohms ±5%, 1/2 w. Composition: 330 ohms ±5%, 1/2 w. Composition: 4700 ohms ±5%, 1/2 w. Composition: 4700 ohms ±5%, 2 w. EXCITER BOARD Al27 199402884G2 4ET57C35 Al39 199402884G2 4ET57C35 Al31 199402884G2 4ET57C35 Al31 199402884G3 4ET57C36 Al31 199402884G3 4ET57C36 Al31 199402884G4 4ET57C36 Al31 199402884G6 4ET57C36 Al32 199402884G6 4ET57C36 Al33 199402884G6 4ET57C36 Al31 199402884G6 4ET57C36 Al31 199402884G6 4ET57C36 Al32 199402884G6 4ET57C36 Al33 199402884G6 4ET57C36 Al31 199402884G7 4ET57C36 Al31 199402884G7 4ET57C36 Al31 199402884G7 4ET57C36 Al32 199402884G7 4ET57C36 Al31 199402884G7 4ET57C36 Al32 199402884G7 4ET57C36 Al31 199402884G7 4ET57C36 Al31 1994028	thru	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW: sim to
Selectro Motive Type DM-15. Sum to Selectro Motive Type DM-15.	C4	5490008P119	Silver mica: 47 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.
Contact, electrical; sim to Bead Chain L93-3.	C5	5490008P121	Silver mica: 56 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.
Contact, electrical; sim to Bead Chain L93-3.		1	JACKS AND RECEPTACLES
R1 3877P393X Composition: 39,000 ohms ±10%, 1/2 w. R2 3877P431J Composition: 430 ohms ±5%, 1/2 w. R5 3R79P183J Composition: 68,000 ohms ±10%, 1/2 w. R6 3R77P21K Composition: 18,000 ohms ±5%, 2 w. R6 3R77P21K Composition: 220 ohms ±10%, 1/2 w. R10 3R77P562K Composition: 5600 ohms ±10%, 1/2 w. R11 3R77P331J Composition: 330 ohms ±5%, 1/2 w. R13 3R78P683K Composition: 330 ohms ±5%, 1/2 w. Composition: 4700 ohms ±5%, 1/2 w. R14 and and R15 R16	thru	4033513P4	Contact, electrical; sim to Bead Chain L93-3.
R2 3R77P431J Composition: 430 ohms ±15%, 1/2 w. R3 3R77P683K Composition: 18,000 ohms ±10%, 1/2 w. R6 3R77P21K Composition: 18,000 ohms ±10%, 1/2 w. R10 3R77P662K Composition: 220 ohms ±10%, 1/2 w. R11 3R77P331J Composition: 5600 ohms ±10%, 1/2 w. R13 3R78P683K Composition: 330 ohms ±5%, 1/2 w. R14 and R15 R16 19A11627SP444 Metal film: 0.28 megohm ±2%, 1/2 w. A127 thru A134 EXCITER BOAD A127 199402884G1 ART57C30 A128 199402884G2 ART57C31 A129 199402884G4 ART57C35 A131 199402884G4 ART57C35 A132 199402884G6 ART57C37 A133 199402884G6 ART57C37 A133 199402884G6 ART57C37 A134 199402884G8 ART57C37 A135 199402884G8 ART57C37 A136 199402884G8 ART57C30 A128 199402884G8 ART57C31 A128 199402884G8 ART57C31 A128 19940284G8 ART57C31 A128 199402884G8 ART57C31 A136 19940284G8 ART57C30 A128 19940284G8 ART57C31 A136 19940284G8 ART57C31 A136 19940284			RESISTORS
R3 3R77P683K Composition: 68,000 ohms ±10%, 1/2 w. R5 3R79P183J Composition: 18,000 ohms ±10%, 1/2 w. R6 3R77P22IK Composition: 220 ohms ±10%, 1/2 w. R10 3R77P33LJ Composition: 5600 ohms ±10%, 1/2 w. R11 3R77P33LJ Composition: 330 ohms ±5%, 1/2 w. R13 3R78P683K Composition: 68,000 ohms ±10%, 1 w. R14 and R15 R16 19A11627SP444 Metal film: 0.28 megohm ±2%, 1/2 w. A127 thru A134 EXCITER BOARD A127 199402884G2 4RT57C30 A128 199402884G4 4RT57C31 A129 199402884G4 4RT57C31 A130 199402884G4 4RT57C35 A131 199402884G6 4RT57C36 A132 199402884G6 4RT57C36 A132 199402884G6 4RT57C36 A132 199402884G6 4RT57C37 A133 199402884G6 4RT57C37 A133 199402884G6 4RT57C37 A134 199402884G6 AT57C37 A134 199402884G6 AT57C37 A134 199402884G6 AT57C37 A134 199402884G6 AT57C37 A135 199402884G6 AT57C37 A155 A155 A155 A155 A155 A155 A155 A15	Rl	3R77P393K	Composition: 39,000 ohms ±10%, 1/2 w.
R5 3R79P183J Composition: 18,000 ohms ±10%, 1/2 w. R10 3R77P221K Composition: 220 ohms ±10%, 1/2 w. R11 3R77P331J Composition: 5600 ohms ±10%, 1/2 w. R13 3R78P683K Composition: 68,000 ohms ±10%, 1/2 w. R14 3R79P472J Composition: 4700 ohms ±10%, 1 w. Composition: 4700 ohms ±5%, 2 w. R15 R16 19A116278P444 Metal film: 0.28 megohm ±2%, 1/2 w. EXCITER BOARD A127 19D40288464 4R757C30 A128 19D40288463 4R757C34 A130 19D40288464 4R757C35 A131 19D40288464 4R757C35 A131 19D40288464 4R757C35 A131 19D40288468 4R757C37 A133 19D40288468 4R757C37 A133 19D40288468 4R757C37 A133 19D40288468 4R757C37 A134 19D40288468 4R757C37 A133 19D40288468 4R757C37 A133 19D40288468 4R757C37 C2 19A116080P3 Polyester: .032 μf ±20%, 50 VDCW. C3 19A116080P4 Polyester: .033 μf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P5 Polyester: .047 μf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 μf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 7491395P109 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 7491395P109 Ceramic disc: 168 pf ±5%, 500 VDCW; sim to RMC Type JL. C8 7491395P109 Ceramic disc: 68 pf ±5%, 500 VDCW; sim to RMC Type JL. C9 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Mica: 100 pf ±5%, 100 VDCW; sim to Electro Mica: 150 pf ±5%, 100 VDCW; sim to Electro	R2	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.
R6 3R77P221K Composition: 220 ohms ±10%, 1/2 w. R10 3R77P562K Composition: 5600 ohms ±10%, 1/2 w. R11 3R77P331J Composition: 330 ohms ±5%, 1/2 w. R13 3R78P683K Composition: 68,000 ohms ±5%, 1/2 w. R14 3R79P472J Composition: 4700 ohms ±5%, 2 w. R15 R16 19A116278P444 Metal film: 0.28 megohm ±2%, 1/2 w. A127 thru A127 19P402884G1 4ET57C30 A128 19P402884G2 4ET57C31 A129 19P402884G2 4ET57C31 A129 19P402884G4 4ET57C35 A131 19P402884G4 4ET57C35 A131 19P402884G4 4ET57C35 A131 19P402884G6 4ET57C37 A133 19P402884G8 4ET57C37 A133 19P402884G8 4ET57C37 A133 19P402884G8 4ET57C41 C1 19A116080P3 Polyester: .032 µf ±20%, 50 VDCW. C2 19A116080P4 Polyester: .033 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 7491395P109 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 7491395P109 Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	R3	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.
R10 3R77P562K Composition: 5600 ohms ±10%, 1/2 w. R11 3R77P331J Composition: 330 ohms ±5%, 1/2 w. R13 3R78P683K Composition: 68,000 ohms ±10%, 1 w. Composition: 4700 ohms ±5%, 2 w. R14 and R15 R16 19A116278P444 Metal film: 0.28 megohm ±2%, 1/2 w. A127	R5	3R79P183J	Composition: 18,000 ohms ±5%, 2 w.
R11 R13 R14 R14 R15 R14 R15 R16 R16 R16 R16 R16 R179P472J R17 R17 R17 R17 R17 R18 R18 R19	R6	3R77P221K	Composition: 220 ohms ±10%, 1/2 w.
R13 R14 and R15 R16 19A116278P444 Metal film: 0.28 megohm ±2%, 1/2 w. EXCITER BOARD Al27 19D40288461 4ET57C30 Al28 19D40288463 4ET57C31 Al30 19D40288464 4ET57C34 Al30 19D40288464 4ET57C36 Al31 19D40288464 4ET57C36 Al31 19D40288464 4ET57C36 Al31 19D40288466 4ET57C36 Al32 19D40288466 4ET57C36 Al32 19D40288467 4ET57C36 Al33 19D40288467 4ET57C36 Al34 19D40288468 4ET57C36 Al34 19D40288468 4ET57C36 Al34 19D40288468 4ET57C36 Al36 19D40288468 4ET57C36 Al37 19D40288468 4ET57C36 Al38 19D40288468 4ET57C36 Al38 19D40288468 4ET57C36 Al39 19D40288468 4ET57C36 Al30 19D40288468 4ET57C36 Al31 19D40288468 4ET57C36 Al32 19D40288468 4ET57C36 Al32 19D40288468 4ET57C36 Al36 19D40288468 4ET57C36 Al37 19D40288468 4ET57C36 Al38 19D40288468 4ET57C30 Al38 19D40288468 4ET57C36 Al38 19	R10	3R77P562K	Composition: 5600 ohms ±10%, 1/2 w.
R14 and R15 R16 19A116278P444 Metal film: 0.28 megohm ±2%, 1/2 w. EXCITER BOARD A127 19D402884G1 4ET57C30 A128 19D402884G2 4ET57C31 A129 19D402884G4 4ET57C34 A130 19D402884G4 4ET57C36 A131 19D402884G6 4ET57C37 A131 19D402884G6 4ET57C37 A133 19D402884G6 4ET57C37 A134 19D402884G6 4ET57C40 A134 19D402884G8 4ET57C41 C1 19A116080P3 Polyester: .022 µf ±20%, 50 VDCW. C2 19A116080P4 Polyester: .033 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 C5 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19A116080P7 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 C10 5496219P359 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to Emery Ju. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 S493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	Rll	3R77P331J	Composition: 330 ohms ±5%, 1/2 w.
### ### ##############################			Composition: 68,000 ohms ±10%, 1 w.
A127 thru A134 EXCITER BOARD A128 19D40288462 4ET57C30 A128 19D40288463 4ET57C31 A129 19D40288463 4ET57C34 A130 19D40288464 4ET57C35 A131 19D40288464 4ET57C36 A132 19D40288466 4ET57C36 A132 19D40288466 4ET57C37 A133 19D40288466 4ET57C40 A134 19D40288468 4ET57C41 C1 19A116080P3 Polyester: .022 µf ±20%, 50 VDCW. C2 19A116080P4 Polyester: .033 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P7 Polyester: .047 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 7491395P109 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 7491395P109 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	and	3R79P472J	Composition: 4700 ohms ±5%, 2 w.
A127 19D40284G1 4ET57C30 A128 19D402884G2 4ET57C31 A128 19D402884G2 4ET57C31 A128 19D402884G3 4ET57C34 A130 19D402884G4 4ET57C35 A131 19D402884G4 4ET57C35 A131 19D402884G6 4ET57C36 A132 19D402884G6 4ET57C37 A133 19D402884G6 4ET57C37 A134 19D402884G6 4ET57C40 A134 19D402884G7 4ET57C40 A134 19D402884G7 4ET57C41 C1 19A116080P3 Polyester: .022 µf ±20%, 50 VDCW. C2 19A116080P4 Polyester: .033 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 C10 5496219P359 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	R16	19A116278P444	Metal film: 0.28 megohm ±2%, 1/2 w.
C1 19A116080P3 Polyester: .022 µf ±20%, 50 VDCW. C2 19A116080P4 Polyester: .033 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	thru		A127 199A02884G1 4ET57C30 A128 199A02884G2 4ET57C31 A129 199A02884G3 4ET57C34 A130 199A02884G4 4ET57C35 A131 199A02884G5 4ET57C36 A132 199A02884G6 4ET57C37 A133 199A02884G7 4ET57C40
C1 19A116080P3 Polyester: .022 µf ±20%, 50 VDCW. C2 19A116080P4 Polyester: .033 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro			
C2 19A116080P4 Polyester: .033 µf ±20%, 50 VDCW. C3 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 C10 5496219P359 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	C1	19A116080P3	
C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15.	C2	19A116080P4	
RMC Type JL. C5 19Al16080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19Al16080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and c9 C10 5496219P359 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C10 5493366P100J Mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	C3	19A116080P7	Polyester: 0.1 µf ±20%, 50 VDCW.
C5 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	C4	7491395P114	Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to
C6 19A116080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	C5	19A116080P7	i
C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 and C9 C10 5496219P359 Ceramic disc: 1000 pf ±10%, 500 VDCW; sim to RMC Type JL. C11 5493366P100J Mica: 100 pf ±5%, 500 VDCW, temp coef Notive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	C6		
and C9 C10 5496219P359 Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	C7	7491395P111	Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to
-150 PPM. C11 5493366P100J Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15. C12 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	and	7491395P109	
Motive Type DM-15. Cl2 5493366P150J Mica: 150 pf ±5%, 100 VDCW; sim to Electro	C10	5496219P359	
	C11	5493366P100J	
	C12	5493366P150J	Mica: 150 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15.
	.,		
-			

ABOL	G-E PART NO	DESCRIPTION	SYMBOL	G-E PART NO	DESCRIPTION
C13	5496219P564	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef		-	JACKS AND RECEPTACLES
C14	5493366P180K	-330 PPM. Mica: 180 pf ±10%, 100 VDCW; sim to Electro	J1 thru	4033513P4	Contact, electrical; sim to Bead Chain L93-3.
C15	5491601P24	Motive Type DM-15. Phenolic: 1.8 pf ±10%, 500 VDCW; sim to Quality	J17		WWW.
		Components Type MC.	L1	19B204526G2	INDUCTORS
C16	5493366P100J	Mica: 100 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15.	L2	19 B2 04526G1	Coil. Includes tuning slug 5491798P2.
C17	5491601P32	Phenolic: 4.7 pf ±10%, 500 VDCW; sim to Quality Components Type MC.			
C18	5496219P561	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef -330 PPM.	Q1 and	19A115123P1	Silicon, NPN; sim to Type 2N2712.
C19	5494481P129	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	Q2 Q3	19A115330Pl	Silicon, NPN.
C20	5494481P128	Ceramic disc: 2700 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	Q4 and	19A115328P1	Silicon, NPN.
C21	5496219P253	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.	Q5 Q6	19A115329P1	Silicon, NPN.
C22	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.		101111002011	
C23	5496219P253	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef	R1	3R77P334K	
204	5406010D055	-80 РРМ.	R2	3R77P105K	Composition: 1 megohm ±10%, 1/2 w.
C24	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.	R3	3R77P562K	Composition: 5600 ohms ±10%, 1/2 w.
C25 and	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R4	3R77P224K	Composition: 0.22 megohm $\pm 10\%$, $1/2$ w.
26		nac type or biscap.	R5	3R77P334K	Composition: 0.33 megohm ±10%, 1/2 w.
227	5496219P440	Ceramic disc: 9.0 pf ±0.5 pf 500 VDCW, temp coef -220 PPM.	R6	3R77P684K	Composition: 0.68 megohm ±10%, 1/2 w.
28	5496219P343	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef	R7	3R77P334K	Composition: 0.33 megohm ±10%, 1/2 w.
229	5491601P35	-150 PPM.	R8	3R77P823K	Composition: 82,000 ohms ±10%, 1/2 w.
-20	0491001733	Phenolic: 0.15 pf ±10%, 500 VDCW; sim to Quality Components Type MC.	R9 R10	3R77P511J 3R77P753J	Composition: 510 ohms ±5%, 1/2 w.
230	5493366P330K	Mica: 330 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.	R11	3R77P274K	Composition: 75,000 ohms ±5%, 1/2 w. Composition: 0.27 megohm ±10%, 1/2 w.
:31	5496219P241	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	R12	19B209358P106	Variable, carbon film: approx 75 to 10,000 ol ±10%, 0.2 w; sim to CTS Type X-201.
32	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef	R13	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.
:33	5496219P51	-80 PPM.	R14	3R77P563K	Composition: 56,000 ohms ±10%, 1/2 w.
.33	5490219P31	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.	R15 and	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.
34	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R16 R17	3R77P222K	Composite to an account of the control of the contr
:35	5496219P35	Ceramic disc: 4.0 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	R18	3R77P433J	Composition: 2200 ohms ±10%, 1/2 w. Composition: 43,000 ohms ±5%, 1/2 w.
36	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to	R19	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.
	5496219P247	RMC Type JF Discap.	R20	3R77P162J	Composition: 1600 ohms ±5%, 1/2 w.
37	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -80 PPM.	R21	3R77P332J	Comosition: 3300 ohms ±5%, 1/2 w.
38	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R22	3R77P162J	Composition: 1600 ohms ±5%, 1/2 w.
:39	5496219P249	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef	R23	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.
		-80 PPM.	R24	3R77P162J	Composition: 1600 ohms ±5%, 1/2 w.
40 hru 42	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R25	3R77P332J	Composition: 3300 ohms ±5%, 1/2 w.
43	5496267P18	Tantalum: 6.8 µf ±20%, 35 VDCW; sim to Sprague	R26 R27	3R77P162J 3R77P103K	Composition: 1600 ohms ±5%, 1/2 w. Composition: 10,000 ohms ±10%, 1/2 w.
		Type 150D,	R28	3R77P272K	Composition: 2700 ohms ±10%, 1/2 w.
44	19A115414P13	Polyester: 0.1 μf ±20%, 200 VDCW.	R29	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.
45	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R30	3R77P392K	Composition: 3900 ohms ±10%, 1/2 w.
		DIODES AND RECTIFIERS	R31	3R77P750J	Composition: 75 ohms ±5%, 1/2 w.
R1	19A115331P1	Silicon.	R32	3R77P121J	Composition: 120 ohms ±5%, 1/2 w.
nd R2			R33	3R77P620J	Composition: 62 ohms ±5%, 1/2 w.
R3	19A115250P1	Silicon.	R34	3R77P121J	Composition: 120 ohms ±5%, 1/2 w.
hru R6			R35	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.
V1	5495769P8	Silicon, capacitive.	R36	3R77P270K	Composition: 27 ohms ±10%, 1/2 w.
			R37 R38	3R77P200J 3R77P363J	Composition: 20 ohms ±5%, 1/2 w.
					Composition: 36,000 ohms ±5%, 1/2 w.

SYM	DESCRIPTION	G-E PART NO	YMBOL
	Metal film: 576,000 ohms $\pm 2\%$, $1/2$ w.	19A116278P474 :	R39
,	Composition: 150 ohms ±10%, 1/2 w.	3R77P151K	R40
	Composition: 47 ohms ±10%, 1/2 w.	3R77P470K	R41
	··, · · ·	3R77P101K	R42
`	Composition: 100 ohms ±10%, 1/2 w.		
	Composition: 0.36 megohm ±5%, 1/2 w.	3R77P364J	R43
Б	Composition: 0.18 megohm ±10%, 1/2 w.	3R77P184K	R44
Б			
F	Coil. Includes tuning slug 5491798P4.	19B204534G1	Tl
, F	Coil. Includes tuning slug 5491798P4.	19B204531G2	Т2
, F	Coil. Includes tuning slug 5491798P4.	19B204535G1	т3
,		19B204535G2	T4
	,,		т5
1	Coil. Includes tuning slug 5491798P4.	19B204537G1	
	Coil. Includes tuning slug 5491798P4.	19B216035G1	Т6
"			
j r	Socket assembly. Includes:	19B216043G1	XY1
F			thru XY4
F	Socket cavity.	19D413071P1	
F	Contact, electrical.	19A115834P2	
I			
1	OSCILLATORS NOTE: When reordering, specify ICOM Frequency.		
	ICOM Frequency = operating frequency - 12. Integrated Circuit Oscillator Module (ICOM).	4EG25A11	Yl
'	Cap, decorative.	19D413070P1	thru Y4
1	cap, decorative.	10011001071	
	CHANNEL GUARD MODIFICATION KIT 19A127078G1 (Used with A131-A134)		
C101			
C102	Polyester: 0.1 µf ±20%, 50 VDCW.	19A116080P7	Cl001 thru
C103			C1004
C104	Composition: 2400 ohms ±5%, 1/2 w.	3R77P242J	R1001
C106	Variable, carbon film: approx 75 to 25,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.	19B209358P107	R1002
C107	Composition: 5100 ohms ±5%, 1/2 w.	3R77P512J	R1003
Cl09			
C110			
C111	Disc: 2500 ohms ±10%, sim to GE 4D403.	19C300048P8	RT1001
C112	LOW PASS FILTER 19C3118O2G1		3101
1			
C113	Polyester: .022 µf ±10%, 50 VDCW.	19A116080P103	C1
C116	Polyester: .022 µf ±20%, 50 VDCW.	19A116080P3	C2
and Cll7	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to	5494481P107	C3
C118	RMC Type JF Discap.	01011017101	•
""	Polyester: 0.22 µf ±20%, 50 VDCW.	19A116080P9	C4
. 1	Polyester: 0.15 µf ±20%, 50 VDCW.	19A116080P8	C5
	Polyester: .022 µf ±20%, 50 VDCW.	19A116080P3	C6
ļ	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to	5494481P107	C7
	RMC Type JF Discap. Polyester: 0.33 µf ±20%, 50 VDCW.	19B209243P14	C8
FL10	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	5494481P111	C13
	JACKS AND RECEPTACLES		
1	Contact, electrical; sim to Bead Chain L93-3.	4033513P4	Jl thru

OL G-E PART NO

19A115123P1

19A115123P1

3R77P333K

3R77P183K

3R77P274K

3R77P822K

3R77P153K 3R77P102K

3R77P183K

3R77P184K

3R77P622J

3R77P330K

3R77P103K

3R77P473K

3R77P103K

3R77P512K

5490828P30

5494481P11

5491271P6

7489162P107

5494481P11

5491498P3

5494481P11

7491398P1

7485975P17

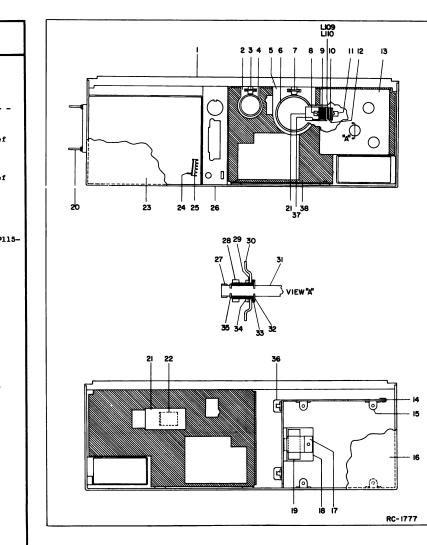
5494481P11

5491271P6

19D402233G5

DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
TRANSISTORS			JACKS AND RECEPTACLES
Silicon, NPN; sim to Type 2N2712.	J101	19C3O3426Gl	Connector: 20 pin contacts.
333333, 333, 332 33 3,72	J102	19B205689Gl	Connector: 18 pin contacts.
Silicon, NPN; sim to Type 2N2712.			
RESISTORS	L101	7488079P35	Choke, RF: 2.2 µh ±10% ind at 790 ma, 0.5 ohm DC res; sim to Jeffers 4412-9K.
Composition: 33,000 ohms ±10%, 1/2 w.	L102	19A121447P2	Coil.
Composition: 18,000 ohms ±10%, 1/2 w.	L103	19A121447P1	Coil.
Composition: 0.27 megohm ±10%, 1/2 w.	L104	7772834P5	Choke, RF: 1.8 µh ind at 1000 ma, approx freq
Composition: 62 ohms ±5%, 1/2 w.	1107	1041010000	range 75-190 MHz; sim to Ohmite Z-144.
Composition: 8200 ohms ±10%, 1/2 w.	L107	19A121239P1 19A121239P2	Coil.
Composition: 15,000 ohms ±10%, 1/2 w.	L109	19B204545P1	Coil.
Composition: 1000 ohms ±10%, 1/2 w.	L110	19B204741P1	Coil.
Composition: 18,000 ohms ±10%, 1/2 w.	Lili	19B204546P1	Coil.
Composition: 0.18 megohm ±10%, 1/2 w.	L112	19B204546P2	Coil.
Composition: 6200 ohms ±5%, 1/2 w.		10000010101	3311.
Composition: 33 ohms ±10%, 1/2 w.			
Composition: 10,000 ohms ±10%, 1/2 w.	P101	4029840P2	Contact, electrical; sim to Amp 42827-2.
Composition: 47,000 ohms ±10%, 1/2 w.	P102	4029840P1	Contact, electrical; sim to Amp 41854.
Composition: 10,000 ohms ±10%, 1/2 w. Composition: 5100 ohms ±10%, 1/2 w.	P103 thru P106	4029840P2	Contact, electrical; sim to Amp 42827-2.
	P107	4029840P1	Contact, electrical; sim to Amp 41854.
Thermistor: 0.33 megohm ±10%, color code black	P108 thru P113	4029840P2	Contact, electrical; sim to Amp 42827-2.
	P114	4029840P1	Contact, electrical; sim to Amp 41854.
CHASSIS 19E500855G1 4ET57C30, 34, 36, 40 19E500855G2 4ET57C31, 35, 37, 41	Pl15 thru Pl17	4029840P2	Contact, electrical; sim to Amp 42827-2.
	P120 and P121	4029840P1	Contact, electrical; sim to Amp 41854.
Ceramic disc: 220 pf ±10%, 500 VDCW, temp coef	Pl22 and Pl23	4029840P2	Contact, electrical; sim to Amp 42827-2.
-5600 PPM.	P124	4029840P1	Contact, electrical; sim to Amp 41854.
Variable, subminiature: approx 2.1-12.7 pf, 750 v peak; sim to EF Johnson 189-6.	Pl 25	4029840P2	Contact, electrical; sim to Amp 42827-2.
Silver mica: 12 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	thru Pl27		
Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to	P128	4033513P17	Contact, electrical; sim to Bead Chain R52-1.
MC Type JF Discap.	Pl 29	4029840P2	Contact, electrical; sim to Amp 42827-2.
Variable: approx 2.8-50 pf, 1700 v peak.			RESISTORS
Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to LMC Type JF Discap.	R101	19A115416P5	Wirewound: 4.38 ohms $\pm 1\%$, 2 w; sim to Dale Type RS-2B.
ariable: approx 3.6-12 pf; sim to Teleradio -9476.			
Ceramic feed-thru: 470 pf ±20%, 750 VDCW; sim o Erie Style 327.	S101	4031922Pl	Push: SPST, normally open, 1/2 amp at 12 VDC; sim to Stackpole SS-15.
eramic disc: 1000 pf ±20%, 1000 VDCW; sim to MC Type JF Discap.	S102	19B209040P1	Slide: DPDT, 0.5 amp at 125 v; sim to Continental Wirt Type 126.
ariable, subminiature: approx 2.1-12.7 pf, 50 v peak; sim to EF Johnson 189-6.			
	TB1	7487424P2	Miniature, phen: 1 terminal.
LOW PASS FILTER ASSEMBLY	TB2	7487424P1	Miniature, phen: 1 terminal.
The output filters are factory tuned. If a filter is found to be defective, it is recommended that	mor		
the entire filter assembly be replaced to maintain ated power output and spurious attenuation.	V101 V102	•	Type 8106. Type 7984.
Lowpass: 132-174 MHz.			2007770
Sarlier than REV A:	Warn Co.		
Lowpass: 132-174 MHz.	XV101	7480532P11	Tube, mica-filled phen: 9 pins rated at 1 amp at 500 VRMS; sim to Elco 04-902-27.

	SYMBOL	G-E PART NO	DESCRIPTION
-	XV102	19C301007P5	Tube, plastic: 12 pins; sim to Alcon Metal Products 371G bottom mount.
-	Z101	19B204543G1	Coil. Includes tuning slug 5491798P4.
.	Cl	5496203P468	Ceramic disc: 510 pf ±5%, 500 VDCW, temp coet -5600 PPM.
	Z102	19B204543G2	Coil. Includes tuning slug 5491798P4.
	Cl	5496203P468	Ceramic disc: 510 pf ±5%, 500 VDCW, temp coef
q			-5600 PPM.
			HARNESS ASSEMBLY 1085008563 (Includes J101, J102, P101-P106, P109-P112, P.
			P117, P120-P127, P129)
	1	19C303395G2	MECHANICAL PARTS (SEE RC-1777) Heat sink.
	2	19B204570P1	Heat sink, tube. (Used with V101).
-	3	19A121195P1	Support. (Used with V101 heat sink).
	4	7165167P5	Insert, tube shield; sim to Atlas 106-332-5. (Used with V101).
	5	19B204571P1	Heat sink, tube. (Used with V102).
	6	7165167P7	Insert, tube shield; sim to Atlas 106-332-18. (Used with V102).
	7	19A121195P2	Support. (Used with V102 heat sink).
	8	N509P608C13	Dowel pin, spring.
	9	19B204756Pl	Insulator, ceramic.
	10	5493361P5	Spring washer; sim to Shakeproof 3502-10-58.
	11	19A122724P1	Post.
	12	N402P39C13	Washer, No. 10.
	13	19B204490G1 4029030P10	Can.
	15	19B204366P1	Channel, rubber. Support.
	16	19C3O3396G3	Mobile bottom cover.
		19C3O3495G2	Station bottom cover.
	17	19A121065P1	Support.
	18	19A121257G1	Angle.
	19	4032591P26	Pad, rubber, adhesive back.
	20	19A121676P1	Guide pin.
-	21	19B204497P1	Shield.
	22	19A121198P1 19C303396G1	Plate line. Mobile top cover.
	"	19C303673G3	Station top cover (Repeaters and VM only).
;		19C303495G8	Station top cover (except Repeaters and VM).
	24	19B204394P1	(Not Used).
	25	19B204393P1	(Not Used).
_	26	19B204395G1	Chassis.
	27	4031527P2	Collar.
	28	4031531P1	Locknut, No. 32.
_	29	7115130P9	Lockwasher; sim to Shakeproof 1220-2.
	30	19B205023P1 19A121189P1	Support. Post. (Used in Models 4ET57C31, 35, 37, 41).
	32	19A121189P2	Post. (Used in Models 4ET57C30, 34, 36, 40).
	33	4031532P1	Cup washer.
- In	34	4031530P1	Bearing, No. 32.
p	35	7165075-P2	Nut, No. 32.
	36	N910P18C	Retaining ring.
	37	19B204776P1	Support.
	38	4036921P1	Mounting support, bottom cover; sim to Tinner C17609-8A-67.
	39	19B204579Gl	Chassis.
	 	1	1



PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

Chassis 19E500855G1, G2

Rev. A - To improve the performance of the transmitter. Changed FL101.

Low Pass Filter 19C311802-G1

Rev. A & B - Incorporated into initial shipment.

10 *COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

PARTS LIST

LBI-3936F

CHANNEL GUARD ENCODER G102 4EH17A10 19C311802G2

SYMBOL	GE PART NO.	DESCRIPTION	R6 R7
UL		SECOND FIOR	R8
		31700	R9
Cla	1941160000100		R10
C1*	19A116080P103	Polyester: 0.022 µf ±10%, 50 VDCW. Earlier than REV A:	R11
	19B209243P2	Polyester: 0.015 µf ±20%, 50 VDCW.	R12
C2	198209243P2 19A116080P3	Polyester: 0.015 µr 120%, 50 VDCW.	R13
C3	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R14 R15
C4	19A116080P9	Polyester: 0.22 µf ±20%, 50 VDCW.	R16
C5	19A116080P8	Polyester: 0.15 µf ±20%, 50 VDCW.	R17
C6	19A116080P3	Polyester: 0.022 µf ±20%, 50 VDCW.	R18
C7	5494481P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R19 R20
C8	19B209243P14	Polyester: 0.33 µf ±20%, 250 VDCW.	R20 R21
C 9	5496267Pl	Tantalum: 6.8 µf ±20%, 6 VDCW; sim to Sprague Type 150D.	R21 R22
C10	19A116080P109	Polyester: 0.22 µf ±10%, 50 VDCW.	R23
C11	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to	
thru C13		RMC Type JF Discap.	RT1
	İ	DIODES AND RECTIFIERS	
CR1 and CR2	19A115250P1	Silicon.	RT2
		TONE NETWORKS	
FL1		TONE FREQUENCY NETWORK 19B205280	W1
	198205280G1 198205280G2 198205280G3 198205280G4 198205280G6 198205280G6 198205280G6 198205280G6 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1 198205280G1	71.9 Hz 77.0 Hz 82.5 Hz 88.5 Hz 94.8 Hz 100.0 Hz 100.5 Hz 11.9 Hz 11.1 Hz 11.1 Hz 11.1 Hz 11.2 Hz 12.3 Hz 12.3 Hz 12.3 Hz 13.6 Hz 13.7 Hz 13.8 Hz 13.6 Hz 14.1 Hz 14.3 Hz 14.3 Hz 14.3 Hz 14.3 Hz 14.3 Hz 14.1 Hz 14.1 Hz 14.2 Hz 15.4 Hz 15.4 Hz 15.5 Hz 17.3 Hz 19.6 Hz 17.3	XFL1
J1 thru J6	4033513P4	Contact, electrical; sim to Bead Chain L93-3.	
		TRANSISTORS	
Q1 and Q2	19A115123P1	Silicon, NPN; sim to Type 2N2712.	
Q3 thru Q5	19A115362P1	Silicon, NPN; sim to Type 2N2925.	
		RESISTORS	}
R1	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.	

SYMBOL	G-E PART NO	DESCRIPTION
R2	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.
R3	3R77P274K	Composition: 0.27 megohms ±10%, 1/2 w.
R4	3R77P620J	Composition: 62 ohms ±5%, 1/2 w.
R5	3R77P822K	Composition: 8200 ohms ±10%, 1/2 w.
R6	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.
R7	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.
R8	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.
R9	3R77P184K	Composition: 0.18 megohms ±10%, 1/2 w.
R10	3R77P622J	Composition: 6200 ohms ±5%, 1/2 w.
R11	3R77P330K	Composition: 33 ohms ±10%, 1/2 w.
R12	19A116278P365	Metal film: 46,400 ohms ±2%, 1/2 w.
R13	3R77P682J	Composition: 6800 ohms ±5%, 1/2 w.
R14	3R77P244J	Composition: 0.24 megohm ±5%, 1/2 w.
R15	19A116278P233	Metal film: 2150 ohms ±2%, 1/2 w.
R16	19A116278P301	Metal film: 10,000 ohms ±2%, 1/2 w.
R17	19A116278P65	Metal film: 46.4 ohms ±2%, 1/2 w.
R18	19A116278P329	Metal film: 19,600 ohms ±2%, 1/2 w.
R19	19A116278P285	Metal film: 7500 ohms ±2%, 1/2 w.
R20	19A116278P412	Metal film: 130,000 ohms ±2%, 1/2 w.
R21	19A116278P269	Metal film: 5110 ohms ±2%, 1/2 w.
R22	19A116278P117	Metal film: 147 ohms ±2%, 1/2 w.
R23	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.
RT1	5490828P30	
RT2	5490828P30 5490828P36	Thermistor: 330,000 ohms ±10%, color code black and gray; sim to Globar Type 783H-3.
R12	5490828P36	Thermistor: 55,000 ohms ±10%, color code black and red; sim to Globar Type 723B.
W1		
XFL1	19A121920G3	Reed, mica-filled phen: 7 pins rated at 1 amp at 500 VRMS with 4-1/4 inches of cable.
		ENCODER INSTALLATION KIT 19A127174G1
		MISCELLANEOUS
	N404P13C13	Lockwasher, no. 6.
	N80P13005C13	Machine screw, no. 6-32 x 5/16.
	19B201074P304	Tap screw, Phillips POZIDRIV®: No. 6-32 x 1/4.
	N210P13C13	Nut, no. 6-32.
	19B205480G2	Harness. Includes:
Pl30 thru	4029840P2	Contact, electrical; sim to Amp 42827-2.
P135		
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*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.